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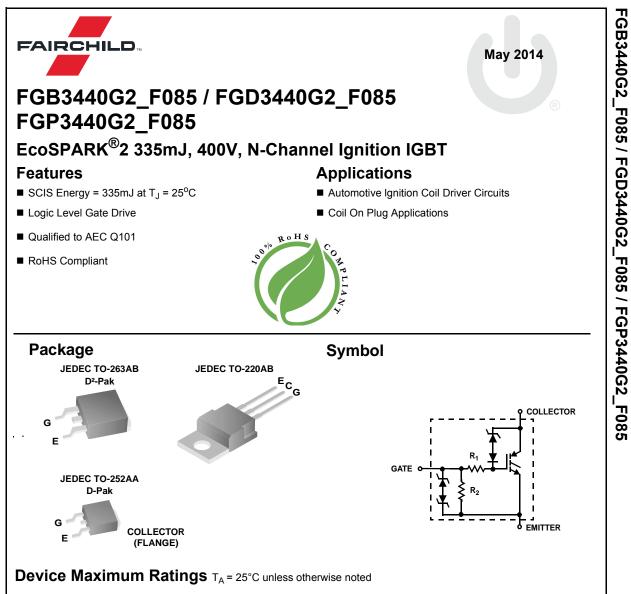


ON Semiconductor®

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Please note: As part of the Fairchild Semiconductor integration, some of the Fairchild orderable part numbers will need to change in order to meet ON Semiconductor's system requirements. Since the ON Semiconductor product management systems do not have the ability to manage part nomenclature that utilizes an underscore (_), the underscore (_) in the Fairchild part numbers will be changed to a dash (-). This document may contain device numbers with an underscore (_). Please check the ON Semiconductor website to verify the updated device numbers. The most current and up-to-date ordering information can be found at www.onsemi.com. Please email any questions regarding the system integration to Fairchild_questions@onsemi.com.

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Symbol	Parameter	Ratings	Units
BV _{CER}	Collector to Emitter Breakdown Voltage (I _C = 1mA)	400	V
BV _{ECS}	Emitter to Collector Voltage - Reverse Battery Condition (I _C = 10mA)	28	V
E _{SCIS25}	Self Clamping Inductive Switching Energy (Note 1)	335	mJ
E _{SCIS150}	Self Clamping Inductive Switching Energy (Note 2)	195	mJ
I _{C25}	Collector Current Continuous, at V _{GE} = 4.0V, T _C = 25°C	26.9	Α
I _{C110}	Collector Current Continuous, at V _{GE} = 4.0V, T _C = 110°C	25	А
V _{GEM}	Gate to Emitter Voltage Continuous	±10	V
П	Power Dissipation Total, at T _C = 25°C	166	W
P _D	Power Dissipation Derating, for T _C > 25°C	1.1	W/ºC
ТJ	Operating Junction Temperature Range	-40 to +175	°C
T _{STG}	Storage Junction Temperature Range	-40 to +175	°C
ΤL	Max. Lead Temp. for Soldering (Leads at 1.6mm from case for 10s)	300	°C
T _{PKG}	Max. Lead Temp. for Soldering (Package Body for 10s)	260	°C
ESD	Electrostatic Discharge Voltage at100pF, 1500 Ω	4	kV

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Packa	ge Mark	ing and Ordering	Information							
Device Marking Device			Package Reel Size Tape		Tape Wi	e Width		Quantity		
FGE	3440G2	FGB3440G2_F085	TO-263AB	330)mm	24mm		800)
FGE)3440G2	FGD3440G2_F085	TO-252AA	330	Omm	16mm			2500	
FGF	3440G2	FGP3440G2_F085	TO-220AB	Tu	ube	N/A			50	
	ical Char	racteristics $T_A = 25^{\circ}$	1							
Symbol		Parameter	Test C	ondit	ions	Mi	n T	ур	Max	Units
Off Stat	te Charact	eristics								
BV _{CER}	Collector to E	mitter Breakdown Voltage	$I_{CE} = 2mA, V_{GE} = 0,$ $R_{GE} = 1K\Omega,$ $T_{J} = -40 \text{ to } 150^{\circ}\text{C}$			37	0 4	00	430	V
BV _{CES}	Collector to E	mitter Breakdown Voltage	$I_{CE} = 10$ mA, $V_{GE} = 0$ R _{GE} = 0, T _J = -40 to 150°C)V,		39	0 4	20	450	V
BV _{ECS}	Emitter to Co	llector Breakdown Voltage	I _{CE} = -20mA, V _{GE} = T _J = 25°C	0V,		28	3	-	-	V
BV _{GES}	Gate to Emitt	er Breakdown Voltage	I _{GES} = ±2mA			±1	2 ±	14	-	V
1	Collector to F	mitter Leakage Current	V _{CE} = 250V, R _{GE} =1	KΩ	T _J = 25°C	-		-	25	μA
ICER		miller Leakaye Guileni			$T_{J} = 150^{\circ}C$	-		-	1	mA
I _{ECS}	Emitter to Co	llector Leakage Current	V _{EC} = 24V,		$T_{J} = 25^{\circ}C$ $T_{J} = 150^{\circ}C$	-		-	1 40	mA
R ₁	Series Gate	Resistance			<u>[.]</u> 100 0	-	1	20	-	Ω
R ₂		er Resistance				10		-	30K	Ω

R2 Gate to Emitter Resistance On State Characteristics

[V _{CE(SAT)}	Collector to Emitter Saturation Voltage	$I_{CE} = 6A, V_{GE} = 4V,$	$T_J = 25^{\circ}C$	-	1.1	1.2	V
ĺ	V _{CE(SAT)}	Collector to Emitter Saturation Voltage	I _{CE} = 10A, V _{GE} = 4.5V,	T _J = 150 ^o C	-	1.3	1.45	V
	V _{CE(SAT)}	Collector to Emitter Saturation Voltage	$I_{CE} = 15A, V_{GE} = 4.5V,$	T _J = 150 ^o C	-	1.6	1.75	V
	E _{SCIS}		L = 3.0 mHy, VGE = 5V RG = 1KΩ, (Note 1)	TJ = 25 ^o C	-	-	335	mJ

Notes:

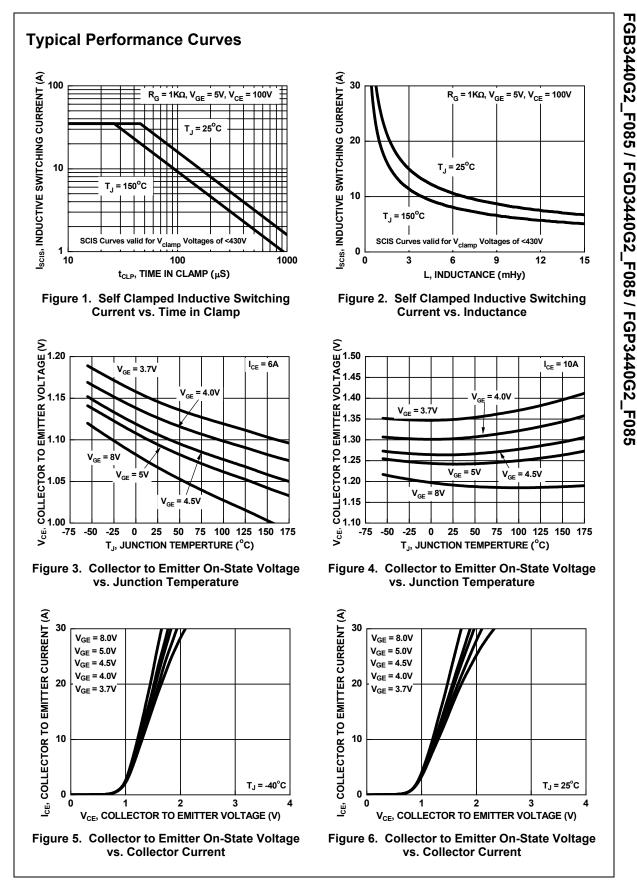
1: Self Clamping Inductive Switching Energy(Escis25) of 335mJ is based on the test conditions that is starting $T_J=25$ °C; L=3mHy, $I_{SCIS}=15A, V_{CC}=100V$ during inductor charging and $V_{CC}=0V$ during the time in clamp . 2: Self Clamping Inductive Switching Energy (Escis150) of 195mJ is based on the test conditions that is starting

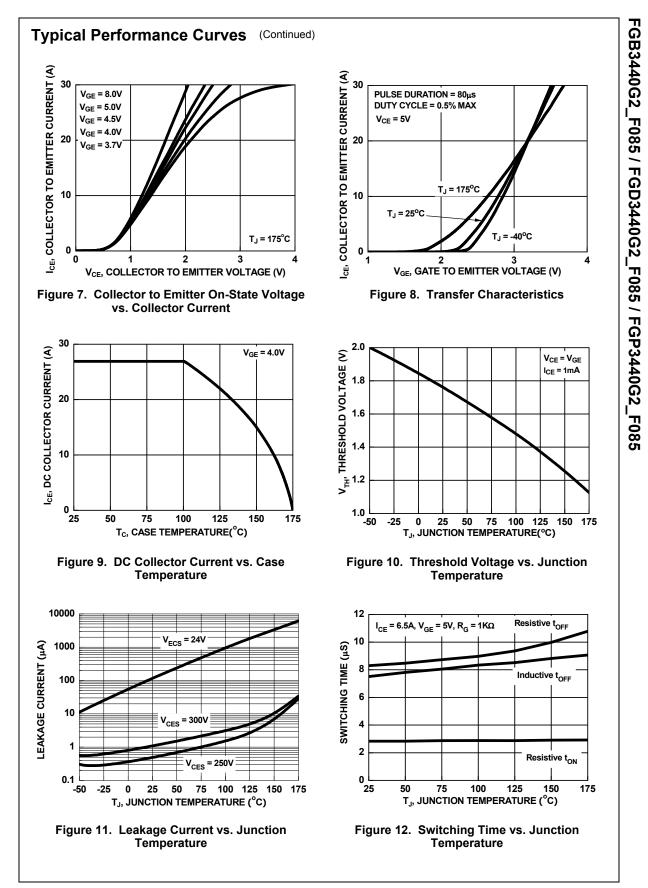
2: Self Clamping Inductive Switching Energy (Escis150) of 195mJ is based on the test conditions that is starting T_J =150 °C; L=3mHy, Iscis=11.4A,Vcc=100V during inductor charging and Vcc=0V during the time in clamp.

$\begin{array}{c c c c c c c c c c c c c c c c c c c $	-		Test Condi	tions	Min	Тур	Max	Units
$\begin{array}{c c c c c c c c c c c c c c c c c c c $		ic Characteristics						
	(ON)	Gate Charge			-	24	-	nC
Switching Characteristics $t_{d(ON)R}$ Current Turn-On Delay Time-Resistive $V_{CE} = 14V, R_L = 1\Omega$ -1.04 t_{rR} Current Rise Time-Resistive $V_{GE} = 5V, R_G = 1K\Omega$ -2.07 $t_{d(OFF)L}$ Current Turn-Off Delay Time-Inductive $V_{CE} = 300V, L = 1mH,$ -5.315 t_{fL} Current Fall Time-Inductive $V_{GE} = 5V, R_G = 1K\Omega$ -2.315Thermal Characteristics	GE(TH)	Gate to Emitter Threshold Voltage	I_{CE} = 1mA, V_{CE} = V_{GE} ,					V
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	GEP	Gate to Emitter Plateau Voltage	V _{CE} = 12V, I _{CE} = 10A		-	2.8	-	V
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	witch	ing Characteristics						
T_{rR} Current Rise Time-Resistive $T_J = 25^{\circ}C$,-2.07 $t_{d(OFF)L}$ Current Turn-Off Delay Time-Inductive $V_{CE} = 300V$, $L = 1mH$, $V_{GE} = 5V$, $R_G = 1K\Omega$ $I_{CE} = 6.5A$, $T_J = 25^{\circ}C$,-5.315Thermal Characteristics	I(ON)R	Current Turn-On Delay Time-Resistive			-	1.0	4	μS
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	R	Current Rise Time-Resistive			-	2.0	7	μS
$I_{CE} = 6.5A, T_J = 25^{\circ}C, \qquad - 2.3 15$ Thermal Characteristics	l(OFF)L	Current Turn-Off Delay Time-Inductive	V _{CE} = 300V, L = 1mH,		-	5.3	15	μS
	L	Current Fall Time-Inductive	V _{GE} = 5V, R _G = 1KΩ I _{CE} =6.5A, T _J = 25 ^o C,		-	2.3	15	μS
R _{0JC} Thermal Resistance Junction to Case - 0.9 ^o	herma	al Characteristics						
	AIC	Thermal Resistance Junction to Case			-	-	0.9	°C/W

FGB3440G2_F085 / FGD3440G2_F085 / FGP3440G2_F085

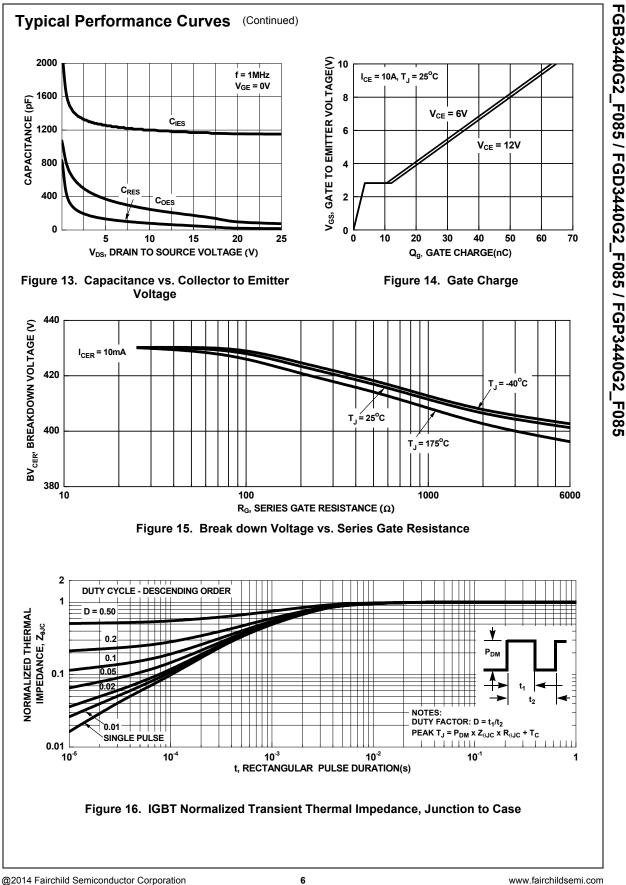
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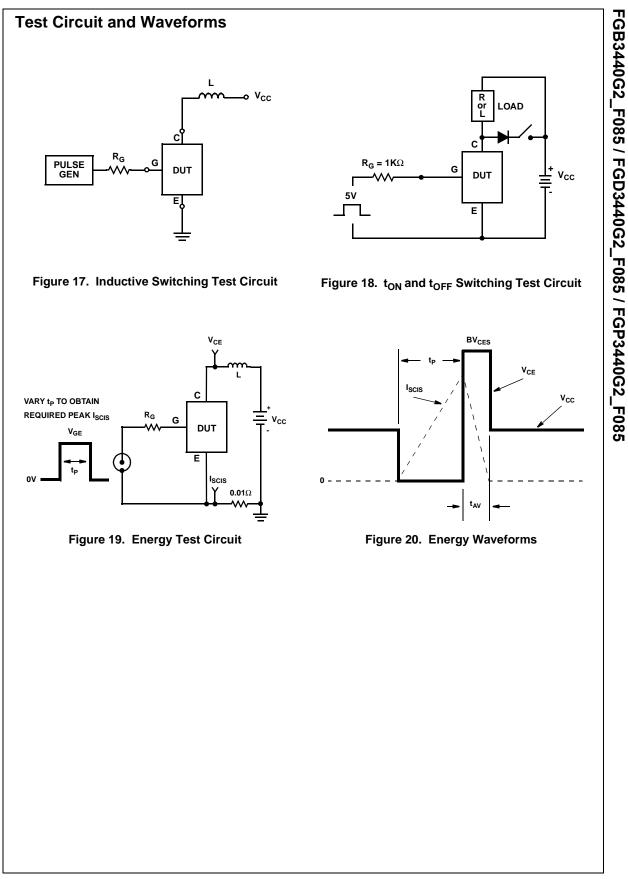


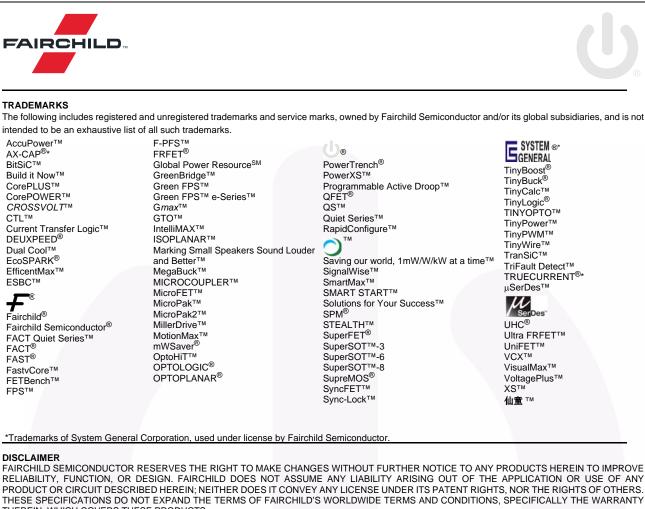
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